

ZXTP2012Z

60V PNP LOW SATURATION MEDIUM POWER TRANSISTOR IN SOT89

SUMMARY

$BV_{CEO} = -60V$; $R_{SAT} = 32m\Omega$; $I_C = -4.3A$

DESCRIPTION

Packaged in the SOT89 outline this new low saturation 60V PNP transistor offers low on state losses making it ideal for use in DC-DC circuits, line switching and various driving and power management functions.



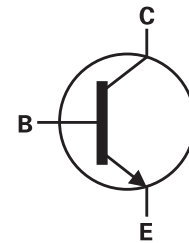
SOT89

FEATURES

- Extremely low equivalent on-resistance; $R_{SAT} = 32mV$ at 5A
- 4.3 amps continuous current
- Up to 15 amps peak current
- Very low saturation voltages
- Excellent gain characteristics specified up to 10 amps

APPLICATIONS

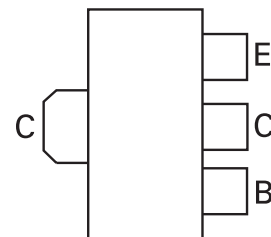
- Emergency lighting circuits
- Motor driving (including DC fans)
- Solenoid, relay and actuator drivers
- DC-DC modules
- Backlight inverters
- Power switches
- MOSFET gate drivers



ORDERING INFORMATION

| DEVICE | REEL SIZE | TAPE WIDTH | QUANTITY PER REEL |
|-------------|-----------|---------------|-------------------|
| ZXTP2012ZTA | 7" | 12mm embossed | 1,000 units |

PINOUT



TOP VIEW

DEVICE MARKING

951

ZXTP2012Z

ABSOLUTE MAXIMUM RATINGS

| PARAMETER | SYMBOL | LIMIT | UNIT |
|--|----------------|-------------|----------------------|
| Collector-base voltage | BV_{CBO} | -100 | V |
| Collector-emitter voltage | BV_{CEO} | -60 | V |
| Emitter-base voltage | BV_{EBO} | -7 | V |
| Continuous collector current ^(a) | I_C | -4.3 | A |
| Peak pulse current | I_{CM} | -15 | A |
| Power dissipation at $T_A = 25^\circ\text{C}$ ^(a) | P_D | 1.5 | W |
| Linear derating factor | | 12 | mW/ $^\circ\text{C}$ |
| Power dissipation at $T_A = 25^\circ\text{C}$ ^(b) | P_D | 2.1 | W |
| Linear derating factor | | 16.8 | mW/ $^\circ\text{C}$ |
| Operating and storage temperature range | T_j, T_{stg} | -55 to +150 | $^\circ\text{C}$ |

THERMAL RESISTANCE

| PARAMETER | SYMBOL | VALUE | UNIT |
|------------------------------------|-----------------|-------|---------------------------|
| Junction to ambient ^(a) | $R_{\theta JA}$ | 83 | $^\circ\text{C}/\text{W}$ |
| Junction to ambient ^(b) | $R_{\theta JA}$ | 60 | $^\circ\text{C}/\text{W}$ |

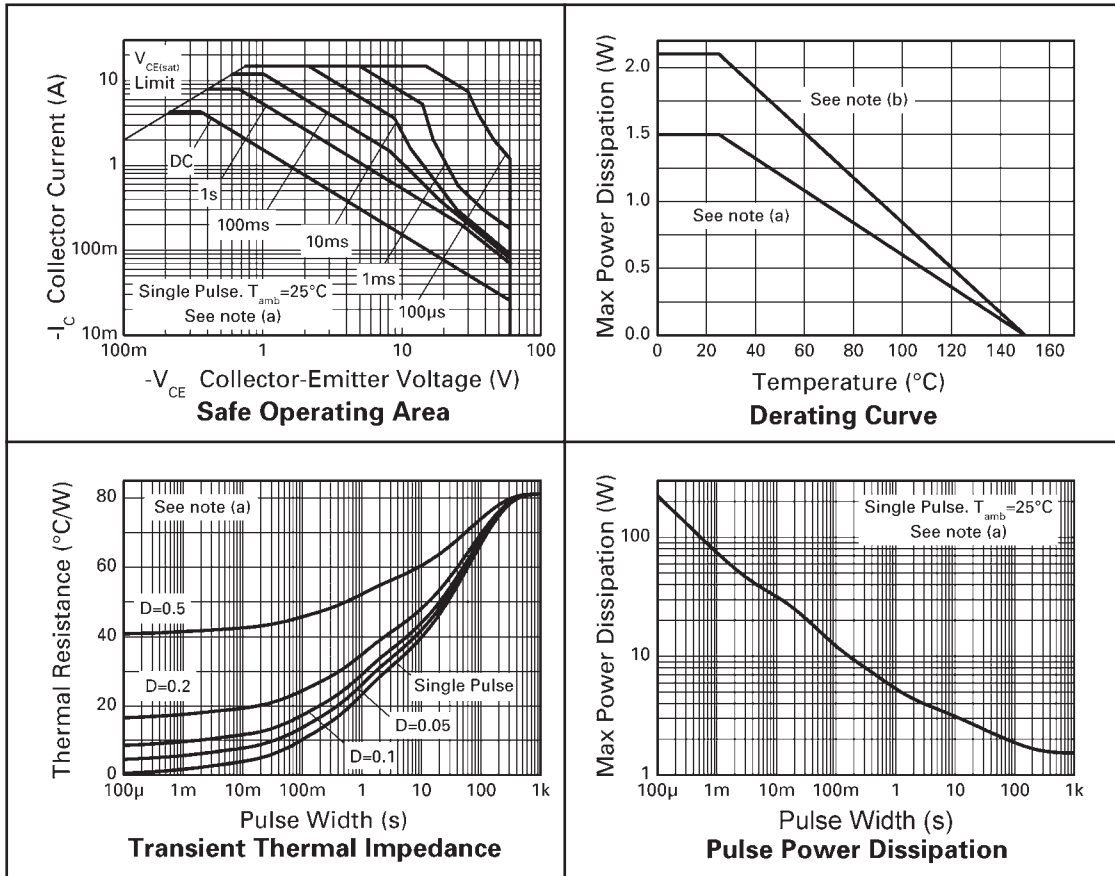
NOTES

(a) For a device surface mounted on 25mm x 25mm x 1.6mm FR4 PCB with high coverage of single sided 1oz copper, in still air conditions.

(b) For a device surface mounted on 50mm x 50mm x 1.6mm FR4 PCB with high coverage of single sided 1oz copper, in still air conditions.

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CHARACTERISTICS



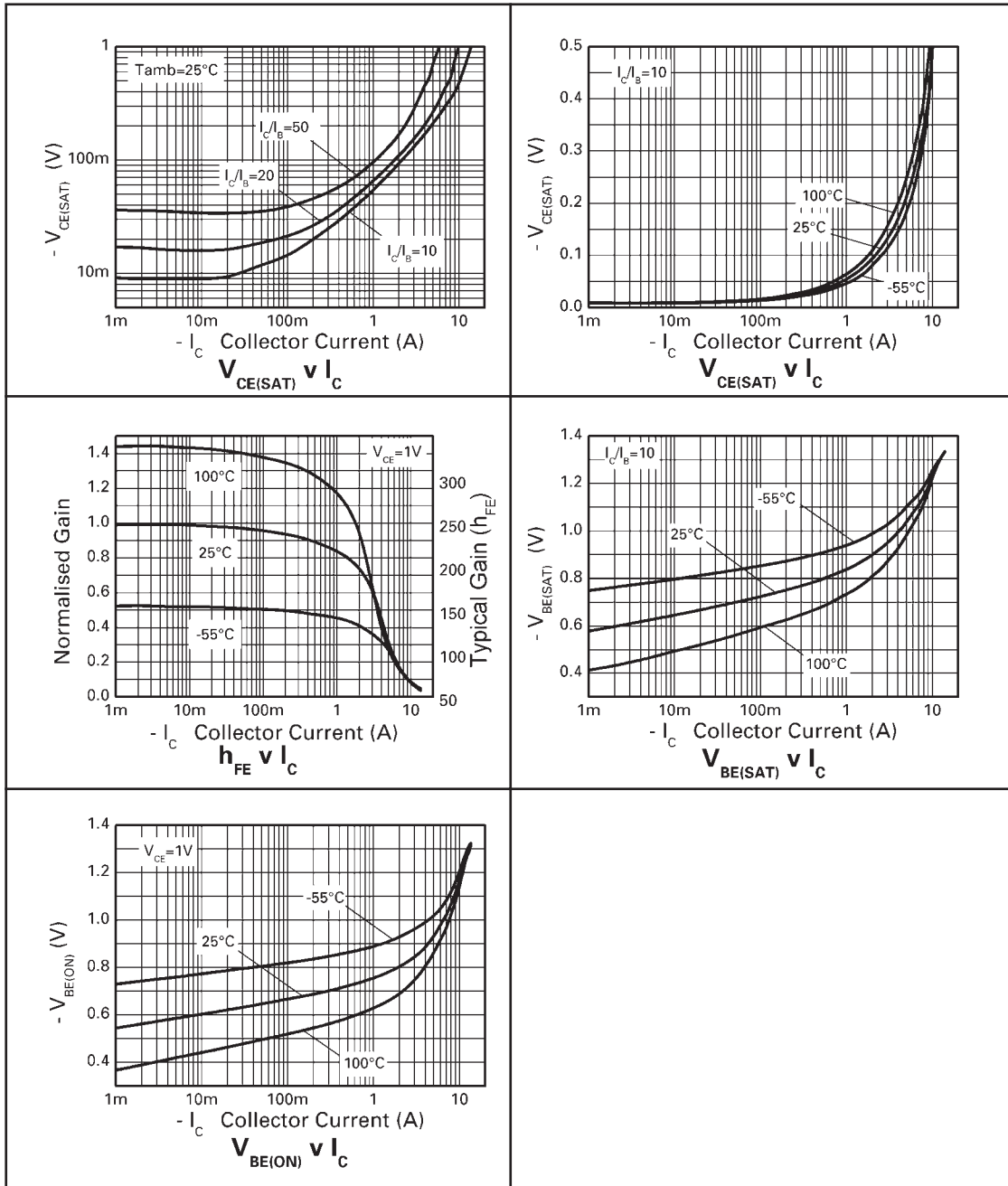
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ELECTRICAL CHARACTERISTICS (at $T_{amb} = 25^{\circ}\text{C}$ unless otherwise stated)

| PARAMETER | SYMBOL | MIN. | TYP. | MAX. | UNIT | CONDITIONS |
|---------------------------------------|---------------------------------------|------------------------|---------------------------|----------------------------|----------------------|---|
| Collector-base breakdown voltage | BV_{CBO} | -100 | -120 | | V | $I_C = -100\mu\text{A}$ |
| Collector-emitter breakdown voltage | BV_{CER} | -100 | -120 | | V | $I_C = -1\mu\text{A}$, $R_B \leq 1\text{k}\Omega$ |
| Collector-emitter breakdown voltage | BV_{CEO} | -60 | -80 | | V | $I_C = -10\text{mA}^*$ |
| Emitter-base breakdown voltage | BV_{EBO} | -7 | -8.1 | | V | $I_E = -100\mu\text{A}$ |
| Collector cut-off current | I_{CBO} | | <1 | -20 -0.5 | nA μA | $V_{CB} = -80\text{V}$ $V_{CB} = -80\text{V}$, $T_{amb} = 100^{\circ}\text{C}$ |
| Collector cut-off current | I_{CER} $R \leq 1\text{k}\Omega$ | | <1 | -20 -0.5 | nA μA | $V_{CB} = -80\text{V}$ $V_{CB} = -80\text{V}$, $T_{amb} = 100^{\circ}\text{C}$ |
| Emitter cut-off current | I_{EBO} | | <1 | -10 | nA | $V_{EB} = -6\text{V}$ |
| Collector-emitter saturation voltage | $V_{CE(SAT)}$ | | -14 -50 -75 -160 | -20 -65 -110 -215 | mV mV mV mV | $I_C = -0.1\text{A}$, $I_B = -10\text{mA}^*$ $I_C = -1\text{A}$, $I_B = -100\text{mA}^*$ $I_C = -2\text{A}$, $I_B = -200\text{mA}^*$ $I_C = -5\text{A}$, $I_B = -500\text{mA}^*$ |
| Base-emitter saturation voltage | $V_{BE(SAT)}$ | | -950 | -1050 | mV | $I_C = -5\text{A}$, $I_B = -500\text{mA}^*$ |
| Base-emitter turn-on voltage | $V_{BE(ON)}$ | | -840 | -950 | mV | $I_C = -5\text{A}$, $V_{CE} = -1\text{V}^*$ |
| Static forward current transfer ratio | H_{FE} | 100 100 45 10 | 250 200 90 25 | 300 | | $I_C = -10\text{mA}$, $V_{CE} = -1\text{V}^*$ $I_C = -2\text{A}$, $V_{CE} = -1\text{V}^*$ $I_C = -5\text{A}$, $V_{CE} = -1\text{V}^*$ $I_C = -10\text{A}$, $V_{CE} = -1\text{V}^*$ |
| Transition frequency | f_T | | 120 | | MHz | $I_C = -100\text{mA}$, $V_{CE} = -10\text{V}$ $f = 50\text{MHz}$ |
| Output capacitance | C_{OBO} | | 48 | | pF | $V_{CB} = -10\text{V}$, $f = 1\text{MHz}^*$ |
| Switching times | t_{ON} t_{OFF} | | 39 370 | | ns | $I_C = -1\text{A}$, $V_{CC} = -10\text{V}$, $I_{B1} = I_{B2} = -100\text{mA}$ |

* Measured under pulsed conditions. Pulse width $\leq 300\mu\text{s}$; duty cycle $\leq 2\%$.

TYPICAL CHARACTERISTICS

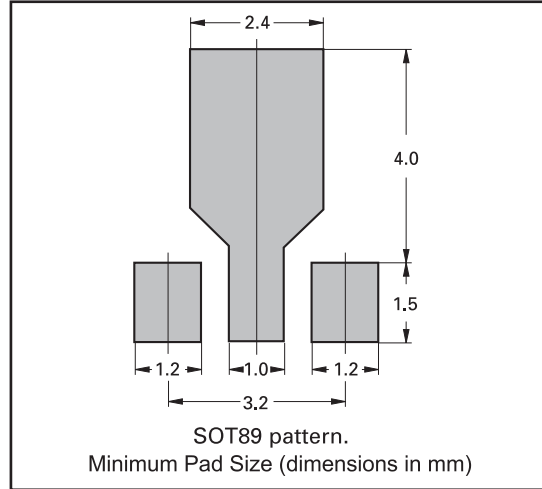


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PACKAGE OUTLINE



PAD LAYOUT DETAILS



Controlling dimensions are in millimeters. Approximate conversions are given in inches

PACKAGE DIMENSIONS

| DIM | Millimeters | | Inches | | DIM | Millimeters | | Inches | |
|-----|-------------|------|--------|-------|-----|-------------|------|--------|-------|
| | Min | Max | Min | Max | | Min | Max | Min | Max |
| A | 1.40 | 1.60 | 0.550 | 0.630 | e | 1.40 | 1.50 | 0.055 | 0.059 |
| b | 0.38 | 0.48 | 0.015 | 0.019 | E | 3.75 | 4.25 | 0.150 | 0.167 |
| b1 | - | 0.53 | - | 0.021 | E1 | - | 2.60 | - | 0.102 |
| b2 | 1.50 | 1.80 | 0.060 | 0.071 | G | 2.90 | 3.00 | 0.114 | 0.118 |
| c | 0.28 | 0.44 | 0.011 | 0.017 | H | 2.60 | 2.85 | 0.102 | 0.112 |
| D | 4.40 | 4.60 | 0.173 | 0.181 | - | - | - | - | - |

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